HALOGEN

FREE



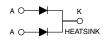
## Vishay General Semiconductor

# **Dual Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.53 \text{ V}$  at  $I_F = 5 \text{ A}$ 







PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 10 A				
$V_{RRM}$	100 V				
I <sub>FSM</sub>	100 A				
V <sub>F</sub> at I <sub>F</sub> = 10 A (T <sub>A</sub> = 125 °C)	0.64 V				
T <sub>J</sub> max.	150 °C				
Package	TO-252 (D-PAK)				
Diode variation	Dual common cathode				

### **FEATURES**

- Trench MOS Schottky technology
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-252 (D-PAK)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V20WM100C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	100	V	
Maximum average forward rectified current (fig. 1)	per device	1	20	Α	
	per diode	I <sub>F(AV)</sub>	10		
Peak forward surge current 8.3 ms single half superimposed on rated load per diode	sine-wave	I <sub>FSM</sub>	100	А	
Operating junction and storage temperature ra	inge	T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.58	-	V
	I <sub>F</sub> = 10 A			0.72	0.82	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.53	-	
	I <sub>F</sub> = 10 A			0.64	0.73	
Reverse current per diode	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub> <sup>(2)</sup>	-	800	μA
	$T_A = 100 \text{ V}$	T <sub>A</sub> = 125 °C		4	24	mA

#### **Notes**

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	V20WM100C	UNIT
Typical thermal resistance	per diode	$R_{ heta JC}$	2.0	°C/W
	per device		1.0	
	per device	R <sub>0JA</sub> (1)(2)	65	

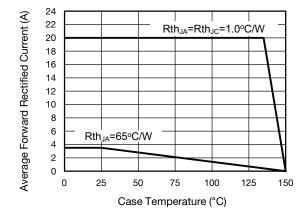
### **Notes**

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta,JA}$ 

(2) Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	BASE QUANTITY	DELIVERY MODE			
V20WM100C-M3/I	0.38	I	2500/reel	13" diameter plastic tape and reel		

### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)





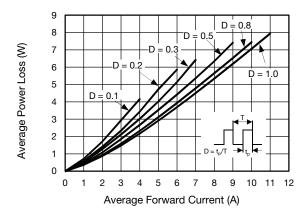


Fig. 2 - Forward Power Loss Characteristics Per Diode



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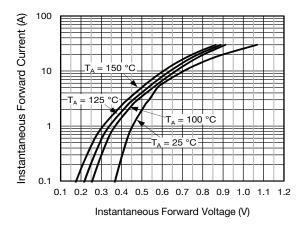


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

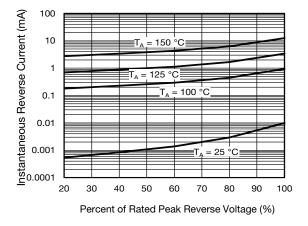


Fig. 4 - Typical Reverse Characteristics Per Diode

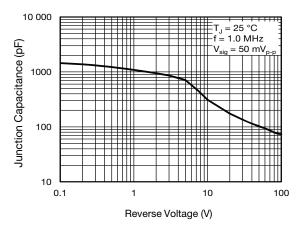


Fig. 5 - Typical Junction Capacitance Per Diode

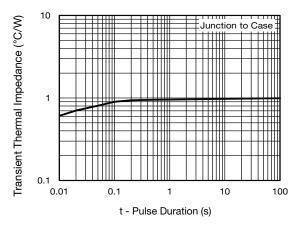
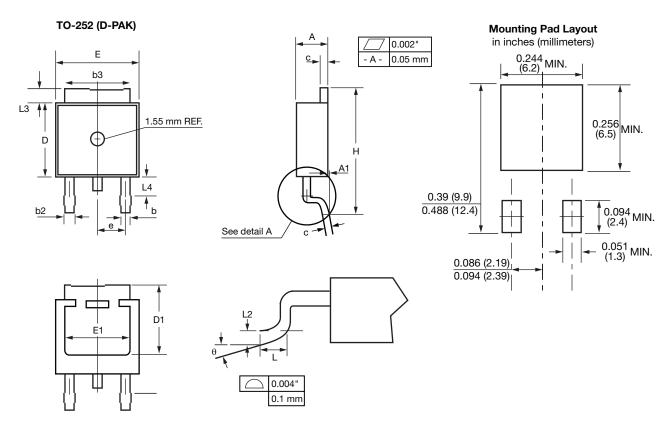


Fig. 6 - Typical Transient Thermal Impedance Per Device



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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



SYMBOL	INC	HES	MILLIMETERS		
	MIN.	MAX.	MIN.	MAX.	
Α	0.086	0.094	2.19	2.38	
A1	-	0.005	-	0.13	
b	0.025	0.035	0.64	0.89	
b2	0.033	0.045	0.84	1.14	
b3	0.205	0.215	5.21	5.46	
С	0.018	0.024	0.46	0.61	
D	0.235	0.250	5.97	6.22	
D1	0.205	-	5.21	-	
Е	0.250	0.265	6.35	6.73	
E1	0.190	-	4.83	-	
е	0.090	0.090 BSC.		BSC.	
Н	0.380	0.410	9.65	10.41	
L	0.055	0.070	1.40	1.78	
L2	0.020	BSC.	0.51 BSC.		
L3	0.035	0.050	0.89	1.27	
L4	0.025	0.039	0.64	1.01	
θ	0°	8°	0°	8°	

#### Note

• Conforms to JEDEC® TO-252 variation AA except dimension "D"

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